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Centimeter-scale 2D perovskite (PEA)₂PbBr₄ single crystal plates grown by a seeded solution method for photodetectors†

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Large-sized single-crystal two-dimensional (2D) perovskites are highly desirable owing to their fundamental properties and intriguing ability to boost devices. Herein, 2-phenylethylammonium lead bromide [(PEA)₂PbBr₄] single crystals, which are a violet-light-emitting 2D perovskite material, with typical lateral sizes of about one centimeter were successfully grown using a seeded solution method. The single-crystal plates showed a well-defined shape (rectangle or hexagon), a natural thickness (300–500 μm) similar to that of conventional silicon and InP wafers, a large aspect ratio of ~20, and a smooth surface (root mean square, ~0.7 nm). We integrated these single crystal plates into an ultraviolet photodetector, achieving a low dark current of ~10⁻¹³ A and an efficient photoresponse (on/off ratio, ~10³). This experiment could easily be extended to grow freestanding 2D perovskite single crystals on a wafer scale for practical integrated optoelectronics.

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Introduction

Organic–inorganic hybrid lead halide perovskites are becoming a hot topic in materials science owing to their solution-based synthesis processes and promising applications in light harvesting and light generation.^{1–4}

In the perovskite family, 2D perovskites naturally form a quantum-well structure with inorganic semiconductor sheets of PbX₄ (X = Cl, Br, or I) as wells and organic layers as dielectric barriers, which further tailor their electronic structure properties.^{5–7} For example, compared with 3D perovskites, 2D perovskites have a higher exciton binding energy and much lower self-doping level, making them excellent candidates for nano-scale lasers and high-performance photodetectors with ultralow thresholds and dark currents, respectively. Furthermore, 2D perovskites exhibit improved thermal stability and moisture resistivity.^{8,9}

In previous studies, most 2D perovskites were polycrystalline films,^{10–13} which suffer from high trap and grain boundary densities. In contrast, single crystals possess much better optoelectrical properties than their polycrystalline counterparts,¹⁴ which has triggered increasing interest in the growth of 2D perovskite single crystals.

Many techniques have been used to grow large-sized 3D hybrid halide perovskite bulk single crystals.^{15–18} For example,

Dang *et al.* and Lian *et al.* adopted a bottom seeded solution temperature-lowering (STL) growth method to grow MAPbI₃ single crystals with centimeter sizes.^{19,20} By combining an inverse temperature crystallization method and repeated seeded growth method, Liu *et al.* grew extra-large MAPbI₃ single crystals²¹ of up to 120 mm²² and FAPbI₃ single crystals of 20 mm.²³ MAPbBr₃ single crystals with a sizes of 44 mm × 49 mm × 17 mm have also been harvested using a low-temperature-gradient crystallization approach.²⁴ Furthermore, smart strategies have been reported to fabricate large-sized single-crystal thin films.^{25–27}

However, directly extending these methods^{28–31} to 2D growth is difficult.^{32–40} The existing growth methods for (PEA)₂PbBr₄ single crystals mainly involve converting polycrystalline thin film to single-crystal nanoplates. Liang *et al.* and Zhai *et al.* adopted a solvent vapor-assisted method to convert spin-coated 2D perovskite (PEA)₂PbBr₄ thin films into well-defined single-crystal microplates,^{34,37} but these methods tended to grow single crystals with small sizes (~10 μm). Wang *et al.* reported a fast synthetic method for preparing inch-scale 2D perovskite single-crystal membranes, which takes advantage of the spontaneous alignment of alkylammonium precursor cations and the high chemical potentials of the precursors molecules at the water–air interface.³⁹ However, the resulting samples had irregular shapes and were too thin to be used without a support substrate. More recently, Zhang *et al.* reported a 200 mm² (PEA)₂PbBr₄ single crystal prepared using a controlled evaporation process.⁴⁰

Herein, large-sized single crystals of (PEA)₂PbBr₄ were grown using a combing STL and seed crystal method. The single

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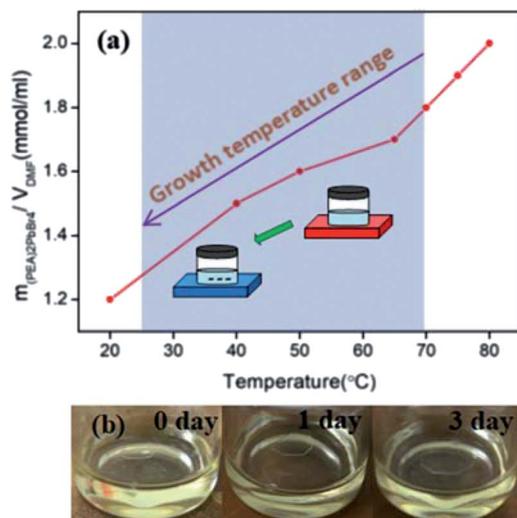


Fig. 1 (a) The temperature-dependent solubility of $(\text{PEA})_2\text{PbBr}_4$ in DMF (red line). Inset: a schematic illustration of the seed crystal growth process. (b) Single crystal growth at different intervals (fresh seed crystal, after 1 day, and after 3 days).

crystal had a large aspect ratio (~ 20) caused by anisotropic growth. The absorption spectrum was unique owing to the absorption of the organic layer. The photoluminescence (PL)

lifetime was longer than those of the thin films, nanoplates, and single crystals reported previously. Finally, we successfully integrated this single crystal plate into a photodetector.

Experimental

The growth method was based on the positive slope of the solubility curve of $(\text{PEA})_2\text{PbBr}_4$ in *N,N*-dimethylformamide (DMF), as shown in Fig. 1(a).

Remarkably, the solubility decreased almost two-fold upon cooling from 80 to 20 °C. The growth process consisted of two steps, as follows: (i) obtaining small single crystal seeds by naturally cooling the saturated solution, and (ii) seed crystals freely growing into large single crystals at room temperature. The precursor solution (1.8 M) was prepared by mixing PEABr and PbBr_2 in a 2 : 1 molar ratio in DMF in a vial and then heating with a hot plate to 70 °C under constant stirring. Once the precursors had dissolved completely, the hot plate was switched off. As the solution temperature dropped from 70 to 25 °C to induce solute saturation, small (~ 1 mm) single crystal microplates were precipitated within a day. A suitable microplate was then selected as the seed crystal and placed into freshly saturated precursor solution in another vial. The seed crystal grew to a centimeter in size in three days. The growth

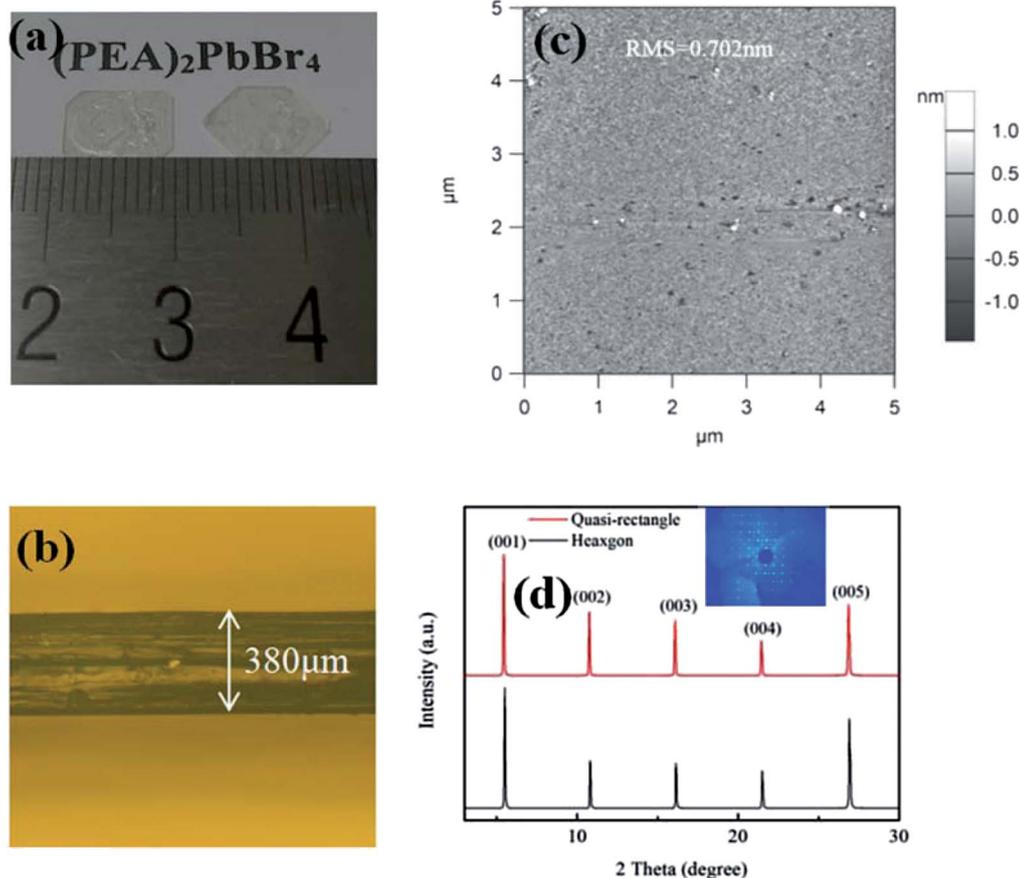


Fig. 2 (a) An optical image of a $(\text{PEA})_2\text{PbBr}_4$ single crystal; (b) single crystal lateral side; (c) AFM image; and (d) XRD 2θ scan patterns. Inset: (00 l) direction.



process is illustrated by three snapshots at different intervals in Fig. 1(b).

Compared with the previously reported STL method,⁴⁹ no acid was involved in these experiments, making it easier to operate and improving the material utilization rate. The average productivity (ratio of final crystal mass to that of the initial precursor) was about 34.33% in four experiments, which was higher than the theoretical expectation (~33.33%), which was attributed to solvent evaporation during the crystal growth process. Furthermore, the precursor solution was recyclable, allowing solvent and precursor overconsumption to be minimized.

Results and discussion

Fig. 2(a) shows a photograph of two $(\text{PEA})_2\text{PbBr}_4$ single crystal plates grown for one week. The left plate had a well-aligned quasi-rectangular shape with a side length of about 8 mm, while the right plate had a hexagon shape with a maximum diagonal length greater than 1.0 cm. Their thicknesses were about 380 μm (as shown in Fig. 2(b)), which corresponded to an aspect ratio of ~20. The aspect ratio has a significant impact on device fabrication and performance.⁴¹ Bulk 3D perovskite single crystals currently available do not usually allow for direct device fabrication. To solve this problem, Chen *et al.* developed a space-confined method to obtain single-crystal thin films with large aspect ratios,²⁶ and Liu *et al.* used a diamond-wire sawing process to slice bulky crystals into thin wafers.²³ In contrast, depending on anisotropic growth in solution, the $(\text{PEA})_2\text{PbBr}_4$ single crystals obtained in this study were freestanding and ready for device fabrication. The single-crystal surface had a root mean square roughness of 0.702 nm within a $5 \times 5 \mu\text{m}^2$ area characterized by atomic force microscopy (AFM), as shown in Fig. 2(c).

X-ray diffractometry (XRD) is a powerful tool for examining single-crystal quality. X-ray 2θ scan patterns of the single-crystal plates with two shapes on the top surface are shown in Fig. 2(d). The same XRD patterns concluded that these plates had

identical crystal structures. The highest diffraction peaks at 5.36° , 10.66° , 15.98° , 21.34° , and 26.76° were assigned to the (001), (002), (003), (004), and (005) lattice planes of the layered $(\text{PEA})_2\text{PbBr}_4$ structure, respectively.³⁷ The dominance of the (00 l) peaks in the XRD patterns suggested that the c -axis was the normal direction of the plate. The inset of Fig. 2(d) was the diffraction pattern in the (00 l) direction.

We also studied the absorption and PL of $(\text{PEA})_2\text{PbBr}_4$ single crystals. Absorption spectra of the single crystal and polycrystalline thin film are shown as solid green and dotted blue lines in Fig. 3(a), respectively. The absorption spectrum of the thin film indicated a single strong excitonic peak at 402 nm, as reported previously,⁴² which was considerably larger than its band edge.⁴³ In contrast, the absorption spectrum of the single crystal showed two main peaks at 422.5 nm (peak 1) and 395.5 nm (peak 2), which was similar to the results for $(\text{C}_6\text{H}_5\text{-CH}_2\text{NH}_3)_2\text{PbI}_4$ (ref. 6) and $(\text{PEA})_2\text{PbBr}_4$ nanoplates.³⁴ Peak 1 appeared at a lower energy than the PL peak of the single crystal,

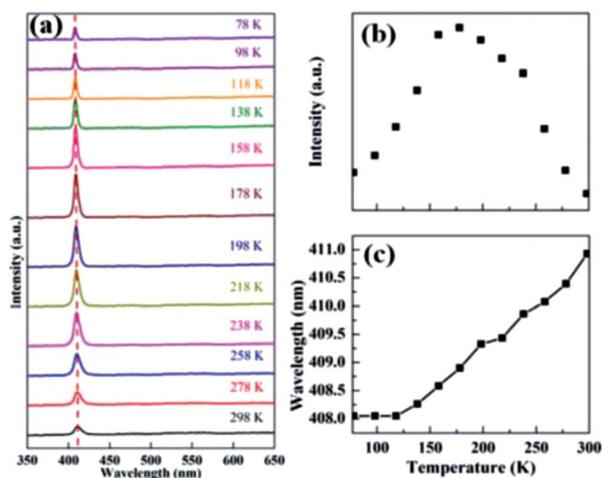


Fig. 4 (a) Temperature-dependent PL spectra from 78 to 298 K; (b) PL peak intensities; (c) PL peak wavelengths.

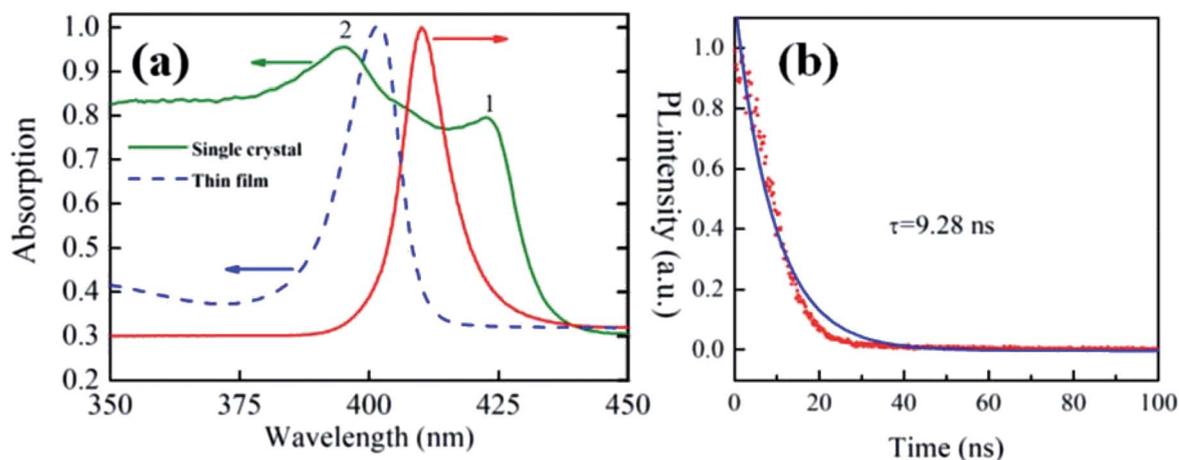


Fig. 3 (a) Absorption spectra of a single crystal (green) and polycrystalline thin film (blue), and PL data from a single crystal (red); (b) time-resolved PL decay.



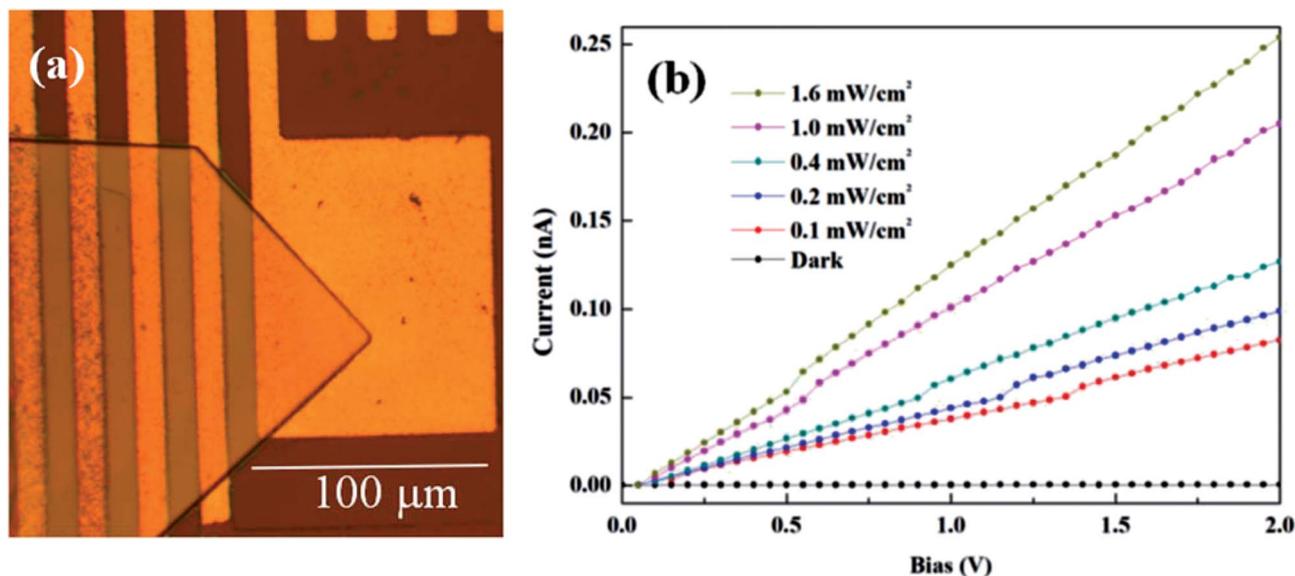


Fig. 5 (a) A microscopic image of a $(\text{PEA})_2\text{PbBr}_4$ -based photodetector. (b) Current–voltage curves of the photodetector illuminated by a 405 nm laser.

indicating that it might be caused by organic layer absorption, which had no corresponding downward radiative transitions. Meanwhile, peak 2, at a shorter wavelength, was attributed to intrinsic exciton absorption.³⁴

The PL lifetime was measured to be 9.28 ns using a time-resolved spectrometer with pulsed 325 nm laser excitation, as shown in Fig. 3(b), which was much longer than those reported for polycrystalline thin films (0.62 ± 0.1 ns),³⁴ nanoplates (1.27 ± 0.02 ns),³⁴ and single crystals prepared using the poor-solvent diffusion method (5.1 ns).⁴² This indicated a longer carrier diffusion length and a lower nonradiative combination rate in the larger single crystals.⁴⁴

Temperature-dependent PL spectroscopy can provide information about phase transitions and optically active defects. The temperature-dependent PL spectra of the $(\text{PEA})_2\text{PbBr}_4$ single crystal from liquid nitrogen temperature (78 K) to room temperature (298 K) are shown in Fig. 4(a). The PL spectrum at each temperature had only a single peak, and the broad defect-related emission reported for $(\text{PEA})_2\text{PbBr}_4$ microplate in ref. 37 was not observed here. Furthermore, the peak intensities increased from 78 to 178 K, reaching a maximum, known as negative thermal quenching behavior,⁴⁵ and then decreasing (Fig. 4(b)), while the band gap peak was slightly red shifted as the temperature increased, as observed for most semiconductors (Fig. 4(c)). Additionally, after being exposed to ambient air for four weeks, the single crystal sample showed no obvious degradation, and its PL intensity remained stable.

Large organic cations (PEA) suppress defect formation, favoring ultralow self-doping concentrations in single crystals of 2D perovskite,³⁶ evoking optoelectronic applications that require ultralow electronic noise, such as photodetectors. Using our growth method, it was easy to grow such a photodetector *in situ* on Au-patterned substrates. Fig. 5(a) illustrates an ultraviolet photodetector made from the single crystal grown using our

method. The Au electrode (channel length, 10 μm) was thermally deposited on a SiO_2 substrate, followed by $(\text{PEA})_2\text{PbBr}_4$ single crystal growth.

This resulted in the fabrication of arrayed $(\text{PEA})_2\text{PbBr}_4$ photoconducting prototype devices based on $(\text{PEA})_2\text{PbBr}_4/\text{Au}$ Schottky contacts. The effective illumination area (active area) of our photodetector was estimated to be $2 \times 10^{-3} \text{ cm}^2$. The photodetector showed an effective photoresponse under ultraviolet 405 nm laser illumination, as shown in Fig. 5(b). The significantly low dark current was $5.56 \times 10^{-13} \text{ A}$ under a bias of 2.0 V. The on/off ratio was about 10^3 at a laser power intensity of 0.1 mW cm^{-2} , which was similar to those reported recently for single crystalline photodetectors.⁴⁰

Conclusions

In summary, we have grown centimeter-scale $(\text{PEA})_2\text{PbBr}_4$ single crystals with a well-defined shape and large aspect ratio using a seeded method, and investigated their efficient photoresponse. This method could also be applied to other 2D perovskite materials to increase their lateral size to the wafer scale for integrated optoelectronic applications.

Conflicts of interest

There are no conflicts of interest to declare.

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